

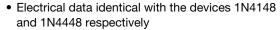
Vishay Semiconductors

Small Signal Fast Switching Diodes



FEATURES

Silicon epitaxial planar diode





AEC-Q101 qualified

ROHS

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Material categorization:
 For definitions of compliance please see www.vishay.com/doc?99912

APPLICATIONS

· Extreme fast switches

MECHANICAL DATA

Case: MiniMELF SOD-80
Weight: approx. 31 mg
Cathode band color: black
Packaging codes/options:

GS18/10K per 13" reel (8 mm tape), 10K/box GS08/2.5K per 7" reel (8 mm tape), 12.5K/box

PARTS TABLE							
PART	TYPE DIFFERENTIATION	ORDERING CODE	TYPE MARKING	INTERNAL CONSTRUCTION	REMARKS		
LL4148	$V_{RRM} = 100 \text{ V},$ $V_{F} = \text{max. } 1000 \text{ mV at } I_{F} = 50 \text{ mA}$	LL4148-GS08 or LL4148-GS18	-	Single diode	Tape and reel		
LL4448	$V_{RRM} = 100 \text{ V},$ $V_{F} = \text{max. } 1000 \text{ mV at } I_{F} = 100 \text{ mA}$	LL4448-GS08 or LL4448-GS18	-	Single diode	Tape and reel		

ABSOLUTE MAXIMUM RATINGS (T _{amb} = 25 °C, unless otherwise specified)						
PARAMETER	TEST CONDITION	SYMBOL	VALUE	UNIT		
Repetitive peak reverse voltage		V _{RRM}	100	V		
Reverse voltage		V_{R}	75	V		
Peak forward surge current	t _p = 1 μs	I _{FSM}	2	Α		
Repetitive peak forward current		I _{FRM}	500	mA		
Forward continuous current		I _F	300	mA		
Average forward current	V _R = 0	I _{F(AV)}	150	mA		
Power dissipation (1)		P _{tot}	500	mW		

Note

⁽¹⁾ Valid provided that electrodes are kept at ambient temperature

THERMAL CHARACTERISTICS (T _{amb} = 25 °C, unless otherwise specified)						
PARAMETER	TEST CONDITION	SYMBOL	VALUE	UNIT		
Thermal resistance junction to ambient air (1)		R _{thJA}	300	K/W		
Junction temperature		TJ	175	°C		
Storage temperature range		T _{sta}	- 65 to + 175	°C		

Note

⁽¹⁾ Valid provided that electrodes are kept at ambient temperature



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ELECTRICAL CHARACTERISTICS (T _{amb} = 25 °C, unless otherwise specified)							
PARAMETER	TEST CONDITION	PART	SYMBOL	MIN.	TYP.	MAX.	UNIT
	I _F = 5 mA	LL4448	V _F	620		720	mV
Forward voltage	$I_F = 50 \text{ mA}$	LL4148	V _F		860	1000	mV
	I _F = 100 mA	LL4448	V_{F}		930	1000	mV
	V _R = 20 V		I_R			25	nA
Reverse current	V _R = 20 V, T _j = 150 °C		I_R			50	μA
	V _R = 75 V		I_R			5	μΑ
Breakdown voltage	$I_R = 100 \mu A, t_p/T = 0.01,$ $t_p = 0.3 \text{ ms}$		V _(BR)	100			V
Diode capacitance	$V_R = 0 \text{ V, f} = 1 \text{ MHz,}$ $V_{HF} = 50 \text{ mV}$		C _D			4	pF
Reverse recovery time	$I_F = I_R = 10 \text{ mA},$ $i_R = 1 \text{ mA}$	- t	+			8	- ns
Theverse recovery time	$I_F = 10 \text{ mA}, V_R = 6 \text{ V}, \\ i_R = 0.1 \text{ x } I_R, R_L = 100 \Omega$		t _{rr}			4	

TYPICAL CHARACTERISTICS (T_{amb} = 25 °C, unless otherwise specified)

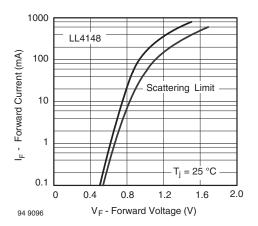


Fig. 1 - Forward Current vs. Forward Voltage

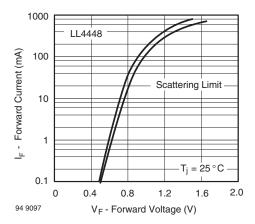


Fig. 2 - Forward Current vs. Forward Voltage

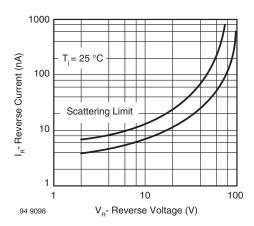


Fig. 3 - Reverse Current vs. Reverse Voltage

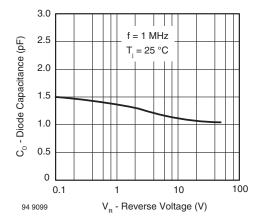
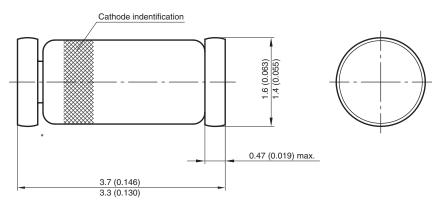


Fig. 4 - Diode Capacitance vs. Reverse Voltage

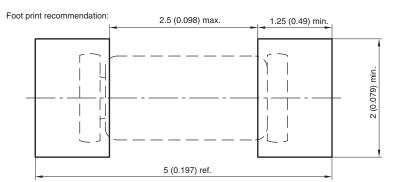


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PACKAGE DIMENSIONS in millimeters (inches): MiniMELF SOD-80



* The gap between plug and glass can be either on cathode or anode side



Document no.:6.560-5005.01-4 Rev. 8 - Date: 07.June.2006 96 12070



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